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ACCEPTED MANUSCRIPT

SILAR deposited Bi₂S₃ thin film towards electrochemical supercapacitor

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Abstract

Bi₂S₃ thin film electrode has been synthesized by simple and low cost successive ionic

layer adsorption and reaction (SILAR) method on stainless steel (SS) substrate at room

temperature. The formation of interconnected nanoparticles with nanoporous surface

morphology has been achieved and which is favourable to the supercapacitor applications.

Electrochemical supercapacitive performance of Bi₂S₃ thin film electrode has been performed

through cyclic voltammetry, charge-discharge and stability studies in aqueous Na₂SO₄

electrolyte. The Bi₂S₃ thin film electrode exhibits the specific capacitance of 289 Fg⁻¹ at 5

mVs⁻¹ scan rate in 1M Na₂SO₄ electrolyte.

Keywords

Thin film; SILAR; Bi₂S₃; supercapacitor.

1 Introduction

Nanostructure materials have attracted considerable scientific interest in the fields of

energy storage devices such as fuel cells, battery and supercapacitor because of their unusual

mechanical, electrical and optical properties endowed by confining the dimensions of

1

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